

### 500V 5A 1.2Ω N-ch Power MOSFET

# **Description**

WMOS R Series is Wayon's 1st generation fast recovery VDMOS family that is dramatic reduction in on-resistance and ultra-low gate charge for applications requiring high power density and high efficiency. And it is very robust and RoHS compliant.

### **TO-252**

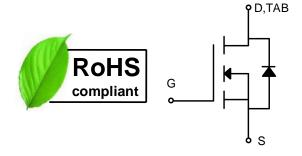


### **Features**

- Typ.R<sub>DS(on)</sub>=1.2 $\Omega$ @V<sub>GS</sub>=10V
- Fast Body Diode
- Fast Switching
- RoHS Compliant

## **Applications**

Motor Control



### **Absolute Maximum Ratings** (Tc=25℃)

Parameter	Symbol	WMD5N50RC	Unit
Drain-source voltage	V <sub>DSS</sub>	500	V
Gate-source voltage	V <sub>GS</sub>	±30	V
Continuous drain current	ΙD	5	А
Pulsed drain current <sup>1</sup>	I <sub>DM</sub>	20	А
Avalanche energy, single pulse <sup>2</sup>	E <sub>AS</sub>	330	mJ
Power dissipation	PD	98	W
Derate above 25°C		0.8	W/°C
Operating junction temperature	Tj	-55~150	°C
Storage temperature	T <sub>stg</sub>	-55~150	°C
Continuous diode forward current	ls	5	Α
Diode pulse current	Spulse	20	А

#### **Thermal Characteristic**

Thermal resistance, junction-to-case	Rejc	1.28	°C/W
Thermal resistance,junction-to-ambient	RθJA	110.0	°C/W





Electrical Characteristics of MOSF	EI
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				Min.	тур.	wax.	
Drain-source break down voltage	BV <sub>DSS</sub>	I <sub>D</sub> =250μA, V <sub>GS</sub> =0V	Tc=25°C	500	ı	-	V
Gate threshold voltage	$V_{GS(th)}$	I <sub>D</sub> =250μA, V <sub>DS</sub> =V <sub>GS</sub>	TJ=25°C	2	-	4	V
Drain course leekege current	1	V <sub>DS</sub> =500V, V <sub>GS</sub> =0V	TJ=25°C	-	-	1	μA
Drain-source leakage current	IDSS	V <sub>DS</sub> =400V, V <sub>GS</sub> =0V	TJ=125°C	-	-	100	μA
Gate-source leakage current,forward	IGSSF	V <sub>DS</sub> =0V, V <sub>GS</sub> =30V	TJ=25°C	-	-	100	nA
Gate-source leakage current,reverse	Igssr	V <sub>DS</sub> =0V, V <sub>GS</sub> =-30V	TJ=25°C	-	-	-100	nA
Drain-source on-state resistance <sup>3</sup>	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =2.5A	TJ=25°C	-	1.2	1.7	Ω
Transconductance <sup>3</sup>	Gfs	V <sub>DS</sub> =20V	TJ=25°C	-	6.2	-	S

## **Dynamic Characteristics of MOSFET** $(T_C=25^{\circ}C)$

Dynamic Characteristics of it	NOSFEI	(TC=25 C)	Min.	Тур.	Max.	
Input capacitance	Ciss	f=1MHz, V <sub>DS</sub> =25V,	-	516	-	pF
Output capacitance	Coss	V <sub>GS</sub> =0V	-	59	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	VGS=0V	-	8	-	pF
Gate to source charge	Q <sub>gs</sub>	V <sub>DD</sub> =240V	-	5	-	nC
Gate to drain charge	$Q_{gd}$	I <sub>D</sub> =5A	-	4	-	nC
Total gate charge	Qg	V <sub>GS</sub> = 0 to10V	-	14	-	nC

## Switching Characteristics of MOSFET (Tc=25°C)

			IVIII I.	ιyp.	iviax.	
Turn-on delay time	t <sub>d on</sub>		-	12	-	ns
Rise time	tr	V <sub>DD</sub> =250V, I <sub>D</sub> =5A,	-	13	-	ns
Turn-off delay time	t <sub>d off</sub>	R <sub>G</sub> =10Ω, V <sub>GS</sub> =10V	-	49	-	ns
Fall time	t <sub>f</sub>		-	19	-	ns

## Characteristics of Body Diode (Tc=25℃)

Characteristics of Body Diou	<b>e</b> (1c=25)	(TC=25 C)		Тур.	Max.	
Forward voltage	V <sub>SD</sub>	I <sub>SD</sub> =5A, V <sub>GS</sub> =0V	-	-	1.4	V
Reverse recovery time	t <sub>rr</sub>	V <sub>DD</sub> =250V, I <sub>S</sub> =5A,	-	86	-	ns
Reverse recovery current	Irr	V <sub>GS</sub> =10V	-	4	-	Α
Recovery charge	Qrr	di/dt=100A/µs	-	0.2	-	μC

#### Notes:

- 1. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}$  =150°C.
- 2. The E\_{AS} data shows Max. rating . The test condition is V\_DD =50V, V\_GS =10V, L=10mH, I\_{AS} =5A,Tc=25 ^{\circ}C .
- 3. The data tested by pulsed , pulse width  $\leq 300 us$  , duty cycle  $\leq 2\%.$



#### TYPICAL CHARACTERISTICS

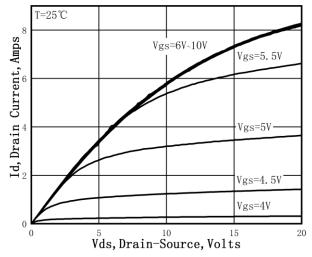


Figure 1.On-Region Characteristics

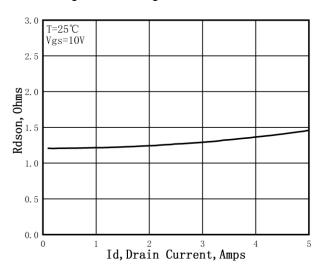


Figure 3. Static Drain-Source On Resistance

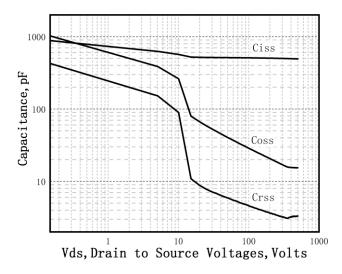


Figure 5 Capacitance Characteristics

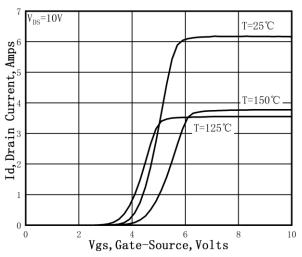


Figure 2. Transfer Characteristics

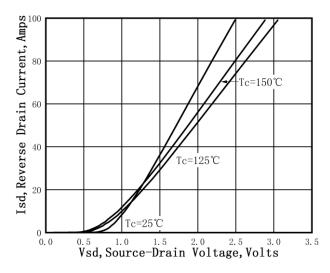


Figure 4. Typical Body Diode Transfer Characteristics

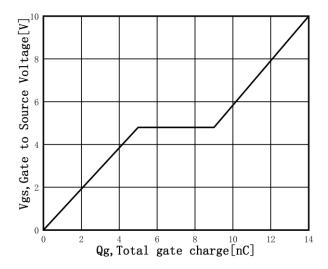


Figure 6. Gate Charge Characteristics





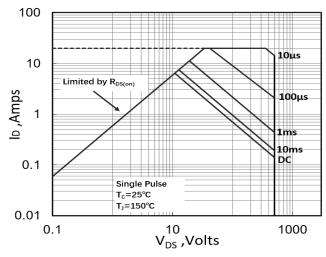


Figure 7. Maximum Safe Operating Area

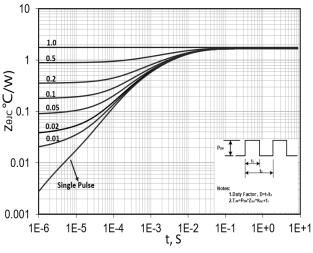
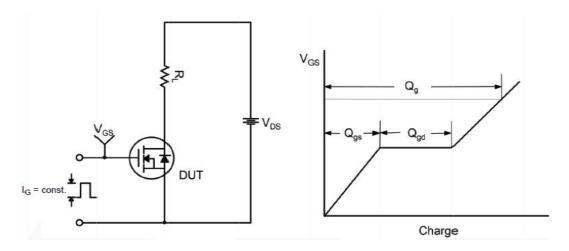


Figure 8. Transient Thermal Response Curve

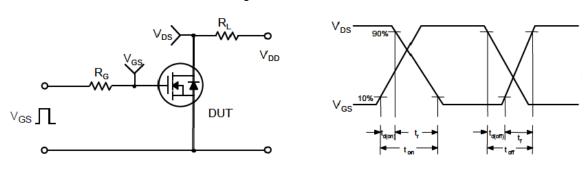


## **Test Circuit**

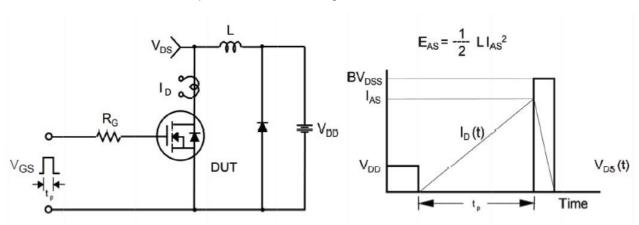
### Gate Charge Test Circuit &Waveform



### Switching Test Circuit &Waveforms

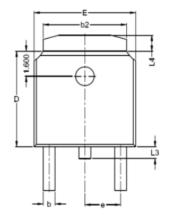


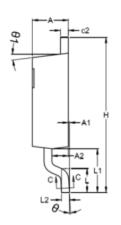
### Unclamped Inductive Switching Test Circuit &Waveforms

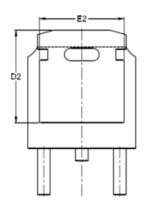




#### **Mechanical Dimensions for TO-252**







#### **COMMON DIMENSIONS**

OVMDOL	MM			
SYMBOL	MIN	MAX		
Α	2.10	2.50		
A1	0	0.15		
b	0.7	0.9		
b2	5.13	5.54		
С	0.44	0.65		
c2	0.45	0.65		
D	6.00	6.20		
D2	5.37	5.78		
Е	6.30	6.90		
E2	4.90	5.30		
e	2.23	2.33		
Ι	9.7	10.5		
L	1.38	1.73		
L1	2.58	3.00		
L2	0.50	0.52		
L3	0.60	1.00		
L4	0.81	1.42		

## **Ordering Information**

Part	Package	Marking	Packing method
WMD5N50RC	TO-252	WMD5N50RC	Tape and reel

### **Contact Information**

No.1001, Shiwan(7) Road, Pudong District, Shanghai, P.R.China.201207 Tel: 86-21-50310888 Fax: 86-21-50757680 Email: market@way-on.com

WAYON website: http://www.way-on.com

For additional information, please contact your local Sales Representative.

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### **Product Specification Statement**

1. The product specification aims to provide users with a reference regarding various product parameters, performance, and usage. It presents certain aspects of the product's performance in graphical form and is intended solely for users to select product and make product comparisons, enabling users to better understand and evaluate the characteristics and advantages of the product. It does not constitute any commitment, warranty, or guarantee.

2. The product parameters described in the product specification are numerical values, characteristics, and functions obtained through actual testing or theoretical calculations of the product in an independent or ideal state. Due to the complexity of product applications and variations in test conditions and equipment, there may be slight fluctuations in parameter test values. WAYON shall not guarantee that the actual performance of the product when installed in the customer's system or equipment will be entirely consistent with the product specification, especially concerning dynamic parameters. It is recommended that users consult with professionals for product selection and system design. Users should also thoroughly validate and assess whether the actual parameters and performance when installed in their respective systems or equipment meet their requirements or expectations. Additionally, users should exercise caution in verifying product compatibility issues, and WAYON assumes no responsibility for the application of the product.

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5. The design of the product is intended to meet civilian needs and is not guaranteed for use in harsh environments or precision equipment. It is not recommended for use in systems or equipment such as medical devices, aircraft, nuclear power, and similar systems, where failures in these systems or equipment could reasonably be expected to result in personal injury. WAYON shall assume no responsibility for any consequences resulting from such usage.

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